

# YG811S04R (5A)

(40V / 5A )

## SCHOTTKY BARRIER DIODE

### ■ Features

- Insulated package by fully molding
- Low VF
- Super high speed switching
- High reliability by planer design

### ■ Applications

- High speed power switching

### ■ Maximum ratings and characteristics

#### • Absolute maximum ratings

Item	Symbol	Conditions	Rating	Unit
Repetitive peak reverse voltage	V <sub>RRM</sub>		40	V
Non-repetitive peak reverse voltage	V <sub>RSM</sub>	t <sub>w</sub> =500ns, duty=1/40	48	V
Isolating voltage	V <sub>iso</sub>	Terminals to Case, AC. 1min.	1500	V
Average output current	I <sub>o</sub>	Square wave, duty=1/2 T <sub>c</sub> =122°C	5	A
Surge current	I <sub>FSM</sub>	Sine wave 10ms	120	A
Operating junction temperature	T <sub>j</sub>		-40 to +150	°C
Storage temperature	T <sub>stg</sub>		-40 to +150	°C

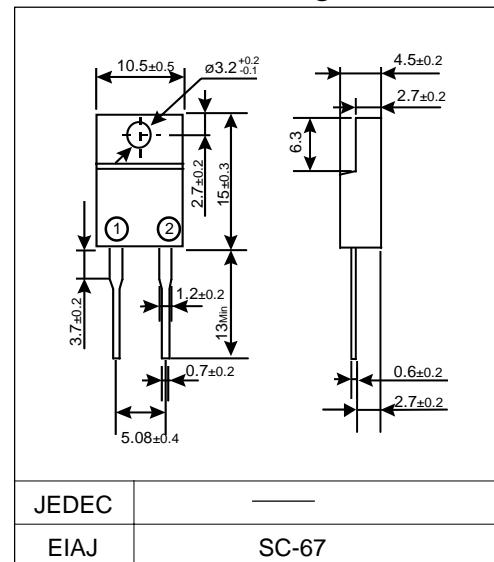
#### • Electrical characteristics (Ta=25°C Unless otherwise specified )

Item	Symbol	Conditions	Max.	Unit
Forward voltage drop	V <sub>FM</sub>	I <sub>FM</sub> =5.0A	0.55	V
Reverse current	I <sub>RRM</sub>	V <sub>R</sub> =V <sub>RRM</sub>	5.0	mA
Thermal resistance	R <sub>th(j-c)</sub>	Junction to case	5.0	°C/W

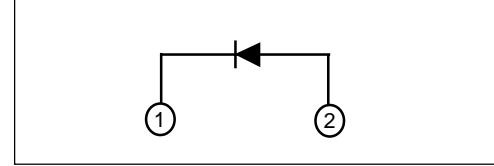
#### • Mechanical Characteristics

Mounting torque	Recommended torque	0.3 to 0.5	N·m
Weight		2.3	g

### ■ Outline drawings, mm



### ■ Connection diagram



## ■ Characteristics

